

CLASSIFICATION

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PATENT NUMBER

U.S. UTILITY Patent Application

O.I.P.E.

PATENT DATE

APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART. UNIT	EXAMINER
09/848718	F	438	586	2012 2012	Berry

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Method of forming a substrate important in a field effect transistor formed over a buried insulator layer

PTO-2040
12/99

ISSUING CLASSIFICATION

Continued on Issue Slip Inside File Jacket

TERMINAL DISCLAIMER		DRAWINGS			CLAIMS ALLOWED	
		Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
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		(Assistant Examiner) _____ (Date)				
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent No. _____					ISSUE FEE	
		(Primary Examiner) _____ (Date)				
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